TRANSMITTAL OF FORMAL DRAWINGS				Docket No. YOR920030293US1 (16818)	
Re Application C	Kang Su Choe, et al.			<u></u>	
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		Address to: Commissioner for Paten P.O. Box 1450 Alexandria, VA 22313-14			
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ansmitted herewi	th are:				
6 she	ets of formal drawing(s) for	or this application.			
Each sheet o	f drawing indicates the id	entifving indicia suggeste	ed in 37 CFR Se	ection 1.84(c).	
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	// // 7		Dated:	May 7, 20	20.4

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I certify that this document and attached formal drawings are being deposited on 5/7/2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Signature of Person Mailing Correspondence

Leslie S. Szivos, Ph.D.

Typed or Printed Name of Person Mailing Correspondence